74LV1T00

2-input single supply translating NAND gate

Rev. 3 — 18 May 2021

Product data sheet

1. General description

The 74LV1T00 is a single, level translating 2-input NAND gate. The low threshold inputs support 1.8 V input logic at $V_{CC} = 3.3$ V and can be used in 1.8 V to 3.3 V level up translation. In addition, the 5 V tolerant input pins enable level down translation (3.3 V to 2.5 V output at $V_{CC} = 2.5$ V). The output level is referenced to the supply voltage and supports 1.8 V, 2.5 V, 3.3 V and 5.0 V CMOS levels. The wide V_{CC} range permits the generation of output levels to connect to controllers or processors.

2. Features and benefits

- Single supply voltage translator at 1.8 V, 2.5 V, 3.3 V and 5.0 V
- Up translation
 - 1.2 V to 1.8 V at V_{CC} = 1.8 V
 - 1.5 V to 2.5 V at V_{CC} = 2.5 V
 - 1.8 V to 3.3 V at V_{CC} = 3.3 V
 - 3.3 V to 5.0 V at V_{CC} = 5.0 V
- Down translation
 - 3.3 V to 1.8 V at V_{CC} = 1.8 V
 - 3.3 V to 2.5 V at V_{CC} = 2.5 V
 - 5.0 V to 3.3 V at V_{CC} = 3.3 V
- · 5 V tolerant inputs
- Latch-up performance exceeds 250 mA per JESD 78 Class II
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - CDM JESD22-C101 exceeds 1 kV
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Applications

- · Portable applications
- PC and notebooks
- Industrial controller
- Telecom



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4. Ordering information

Table 1. Ordering information

Type number	Package	Package							
	Temperature range	Name	Description	Version					
74LV1T00GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
74LV1T00GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753					
74LV1T00GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3					

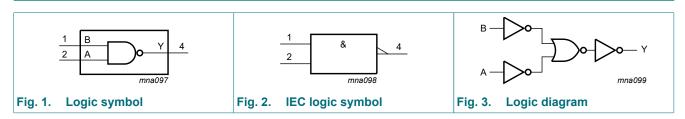
5. Marking

Table 2. Marking

Type number	Marking code[1]
74LV1T00GW	Sa
74LV1T00GV	Sa
74LV1T00GX	Sa

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

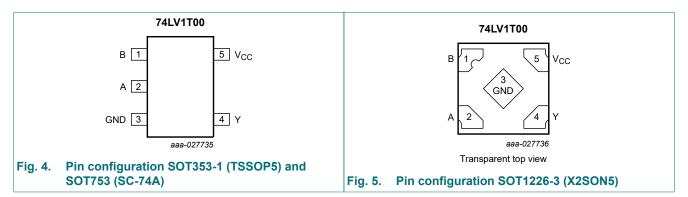
6. Functional diagram



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7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
В	1	data input	
A	2	data input	
GND	3	ground (0 V)	
Υ	4	data output	
V _{CC}	5	supply voltage	

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level

Input		Output	
Α	В	Υ	
L	L	Н	
L	Н	Н	
Н	L	Н	
Н	Н	L	

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage	[1]	-0.5	+7.0	V
V _O	output voltage	output HIGH or LOW state [2]		V _{CC} + 0.5	V
		output in power-off state [2]	-0.5	4.6	V
I _{IK}	input clamping current	V _I < 0 V	-20	-	mA
I _{OK}	output clamping current	$V_O < 0 \text{ V or } V_O > V_{CC}$	-	±20	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [4]	-	250	mW

^[1] If the input current ratings are observed, the minimum input voltage ratings may be exceeded.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.6	5.0	5.5	V
V _I	input voltage		0	-	5.5	V
Vo	output voltage	output HIGH or LOW state	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.8 V to 5.0 V	-	-	20	ns/V

^[2] If the output current ratings are observed, the output voltage ratings may be exceeded.

^[3] This value is limited to 7 V maximum.

^[4] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C. For SOT753 (SC-74A) package: P_{tot} derates linearly with 3.8 mW/K above 85 °C. For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.

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11. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °	C	-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 1.65 V to 1.8 V	0.94	-	1.0	-	1.0	-	٧
	input voltage	V _{CC} = 2.0 V	0.99	-	1.03	-	1.03	-	٧
		V _{CC} = 2.25 V to 2.5 V	1.135	-	1.18	-	1.18	-	٧
		V _{CC} = 2.75 V	1.21	-	1.23	-	1.23	-	V
		V _{CC} = 3.0 V to 3.3 V	1.35	-	1.37	-	1.37	-	٧
		V _{CC} = 3.6 V	1.47	-	1.48	-	1.48	-	٧
		V _{CC} = 4.5 V to 5.0 V	2.02	-	2.03	-	2.03	-	٧
		V _{CC} = 5.5 V	2.10	-	2.11	-	2.11	-	٧
V _{IL}	LOW-level	V _{CC} = 1.65 V to 2.0 V	-	0.58	-	0.55	-	0.55	V
	input voltage	V _{CC} = 2.25 V to 2.75 V	-	0.75	-	0.71	-	0.71	V
		V _{CC} = 3.0 V to 3.6 V	-	0.80	-	0.65	-	0.65	V
		V _{CC} = 4.5 V to 5.5 V	-	0.80	-	0.80	-	0.80	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ;							
	output voltage	V _{CC} = 1.65 V to 5.5 V; I _O = -20 μA	V _{CC} -0.1	-	V _{CC} -0.1	-	V _{CC} -0.1	-	V
		V _{CC} = 1.65 V; I _O = -2 mA	1.28	-	1.21	-	1.21	-	V
		V _{CC} = 1.8 V; I _O = -2 mA	1.5	-	1.45	-	1.45	-	٧
		V _{CC} = 2.3 V; I _O = -2.3 mA	2.0	-	2.0	-	2.0	-	V
		$V_{CC} = 2.3 \text{ V}; I_{O} = -3 \text{ mA}$	2.0	-	1.93	-	1.93	-	V
		V _{CC} = 2.5 V; I _O = -3 mA	2.25	-	2.15	-	2.15	-	٧
		V _{CC} = 3.0 V; I _O = -3 mA	2.78	-	2.7	-	2.7	-	٧
		V _{CC} = 3.0 V; I _O = -5.5 mA	2.6	-	2.49	-	2.49	-	٧
		V _{CC} = 3.3 V; I _O = -5.5 mA	2.9	-	2.8	-	2.8	-	٧
		V _{CC} = 4.5 V; I _O = -4 mA	4.2	-	4.1	-	4.1	-	٧
		V _{CC} = 4.5 V; I _O = -8 mA	4.1	-	3.95	-	3.95	-	V
		V _{CC} = 5.0 V; I _O = -8 mA	4.6	-	4.5	-	4.5	-	٧
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}							
	output voltage	V _{CC} = 1.65 V to 5.5 V; I _O = 20 μA	-	0.1	-	0.1	-	0.1	V
		V _{CC} = 1.65 V; I _O = 2 mA	-	0.2	-	0.25	-	0.25	٧
		V _{CC} = 2.3 V; I _O = 2.3 mA	-	0.1	-	0.15	-	0.15	٧
		$V_{CC} = 2.3 \text{ V}; I_{O} = 3 \text{ mA}$	-	0.15	-	0.2	-	0.2	V
		V _{CC} = 3.0 V; I _O = 3 mA	-	0.1	-	0.15	-	0.15	٧
		V _{CC} = 3.0 V; I _O = 5.5 mA	-	0.2	-	0.252	-	0.252	V
		V _{CC} = 4.5 V; I _O = 4 mA	-	0.15	-	0.2	-	0.2	V
		V _{CC} = 4.5 V; I _O = 8 mA	-	0.3	-	0.35	-	0.35	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 0$ V to 5.5 V	-	±0.1	-	±1	-	±1	μΑ
lcc	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 1.8 V, 2.5 V, 3.3 V, 5.0 V	-	1	-	10	-	10	μA

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Symbol	Parameter	Conditions	25 °C -40 °C		25 °C -40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	Min	Max	
ΔI _{CC}	additional supply current	per input pin; V_{CC} = 1.8 V; V_I = 0.3 V or 1.1 V; I_O = 0 A; other pins at V_{CC} or GND	-	10	-	10	-	10	μΑ
		per input pin; V_{CC} = 5.5 V; V_I = 0.3 V or 3.4 V; I_O = 0 A; other pins at V_{CC} or GND	-	1.35	-	1.5	-	1.5	mA

12. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V. For test circuit, see Fig. 7.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation	A, B to Y; see <u>Fig. 6</u> [1]								
	delay	$V_{CC} = 1.8 \text{ V}; C_L = 15 \text{ pF}$	-	6.4	10.2	-	11.5	-	12.3	ns
		$V_{CC} = 1.8 \text{ V}; C_L = 30 \text{ pF}$	-	7.5	12.0	-	13.4	-	14.4	ns
		V _{CC} = 2.5 V; C _L = 15 pF	-	4.5	6.9	-	7.8	-	8.4	ns
		$V_{CC} = 2.5 \text{ V}; C_L = 30 \text{ pF}$	-	5.3	8.0	-	9.1	-	9.7	ns
		V _{CC} = 3.3 V; C _L = 15 pF	-	3.7	5.6	-	6.2	-	6.6	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 30 \text{ pF}$	-	4.3	6.4	-	7.1	-	7.6	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	3.1	4.2	-	4.6	-	4.8	ns
		V _{CC} = 5.0 V; C _L = 30 pF	-	3.6	4.8	-	5.2	-	5.5	ns
Cı	input capacitance	$V_I = V_{CC}$ or GND; $V_{CC} = 3.3 \text{ V}$	-	1.5	10	-	10	-	10	pF
Co	output capacitance	$V_O = V_{CC}$ or GND; $V_{CC} = 3.3 \text{ V}$	-	2.5	-	-	-	-	-	pF
C _{PD}	power dissipation	per buffer; V_I = GND to V_{CC} ; [2] C_L = 30 pF; f = 10 MHz								
	capacitance	V _{CC} = 1.8 V	-	4.0	-	-	-	-	-	pF
		V _{CC} = 2.5 V	-	5.3	-	-	-	-	-	pF
		V _{CC} = 3.3 V	-	7.1	-	-	-	-	-	pF
		V _{CC} = 5.0 V	-	11.2	-	-	-	-	-	pF

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

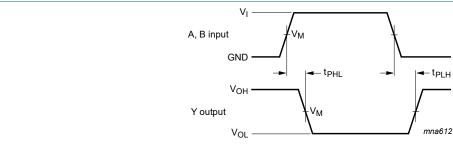
V_{CC} = supply voltage in V;

N = number of inputs switching; $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$

 $[\]begin{array}{ll} [1] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}. \\ [2] & C_{PD} \text{ is used to determine the dynamic power dissipation } (P_D \text{ in } \mu \text{W}). \\ & P_D = C_{PD} \text{ x V}_{CC}^2 \text{ x f}_i \text{ x N} + \sum (C_L \text{ x V}_{CC}^2 \text{ x f}_o) \text{ where:} \end{array}$

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12.1. Waveforms and test circuit



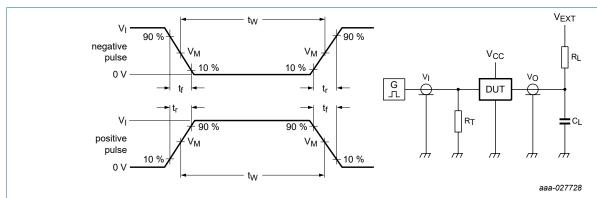
Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 6. The input A, B to output Y propagation delays

Table 9. Measurement points

Input	Output
V_{M}	V_{M}
0.5V _I	0.5V _{CC}



Test data is given in Table 10.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance

V_{EXT} = External voltage for measuring switching times

Fig. 7. Test circuit for measuring switching times

Table 10. Test data

Supply voltage Input			Load		V _{EXT}			
V _{CC}	V _I	Δt/ΔV [1]	f _{max}	C _L	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
1.8 V	V _{CC}	≤ 1.0 ns/V	15 MHz	15 pF, 30 pF	1ΜΩ	GND	GND	V _{CC}
2.5 V	V _{CC}	≤ 1.0 ns/V	25 MHz	15 pF, 30 pF	1ΜΩ	GND	GND	V _{CC}
3.3 V	3 V	≤ 1.0 ns/V	50 MHz	15 pF, 30 pF	1ΜΩ	GND	GND	V _{CC}
5.0 V	3 V	≤ 1.0 ns/V	50 MHz	15 pF, 30 pF	1ΜΩ	GND	GND	V _{CC}

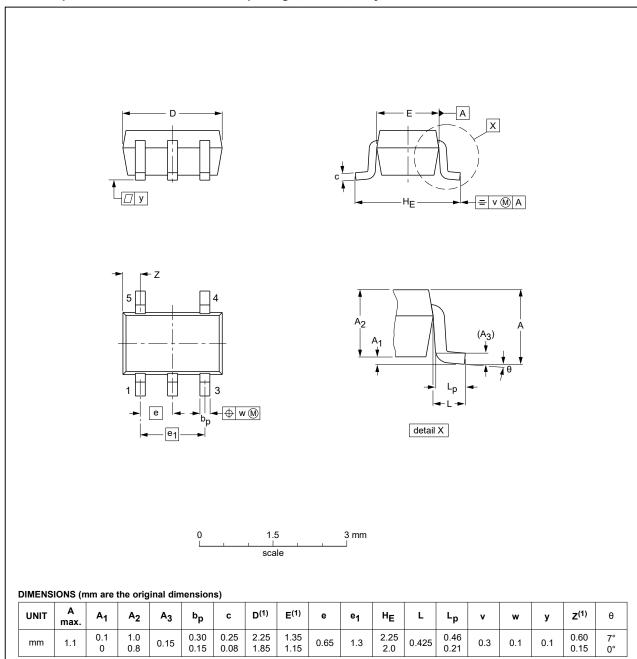
[1] $dV/dt \ge 1.0 V/ns$

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13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			-00-09-01 03-02-19

Fig. 8. Package outline SOT353-1 (TSSOP5)

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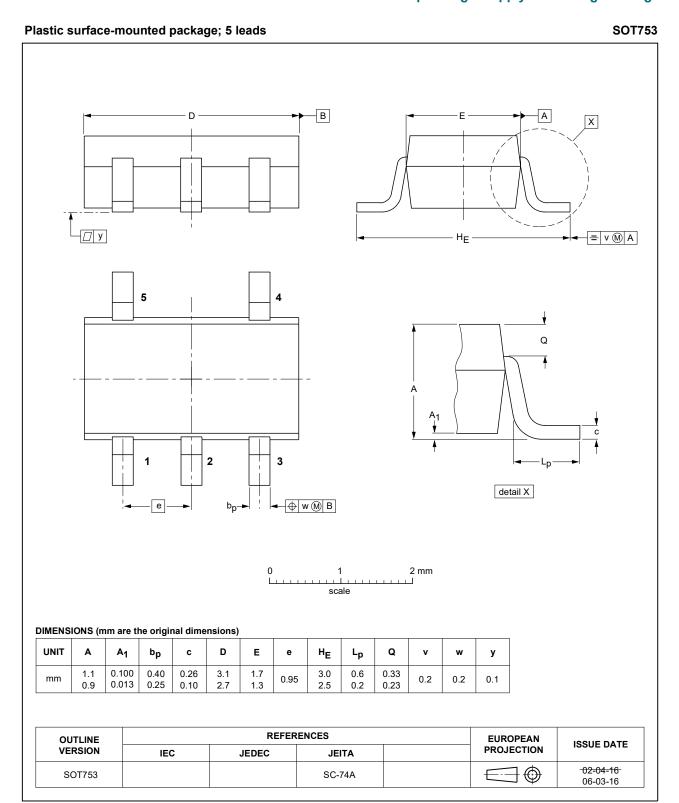


Fig. 9. Package outline SOT753 (SC-74A)

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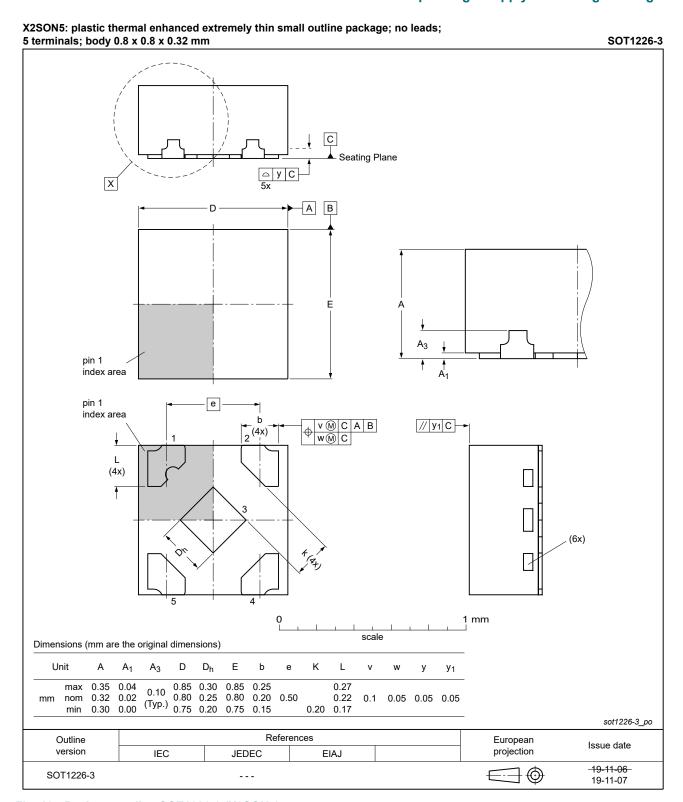


Fig. 10. Package outline SOT1226-3 (X2SON5)

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14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charge Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

15. Revision history

Table 12. Revision history

1444-14-14-14-14-14-14-14-14-14-14-14-14							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74LV1T00 v.3	20210518	Product data sheet	-	74LV1T00 v.2			
Modifications:	• SOT1226 (X2S	package.					
74LV1T00 v.2	20191203	Product data sheet	-	74LV1T00 v.1			
Modifications:	Type number 7-Table 5: Deratir						
74LV1T00 v.1	20171122	Product data sheet	-	-			

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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NLSX4373DMR2G NLSX5012MUTAG NLSX0102FCT2G NLSX4302EBMUTCG PCA9306FMUTAG MC100EPT622MNG
NLSX3014MUTAG NLSV4T244EMUTAG NLSX5011MUTCG NLV9306USG NLVSX4014MUTAG NLSV4T3144MUTAG
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ADG32233BRMZ ADG3241BKSZ-500RL7